

Operating mechanisms of mesoscopic perovskite solar cells through impedance spectroscopy and J-V modeling

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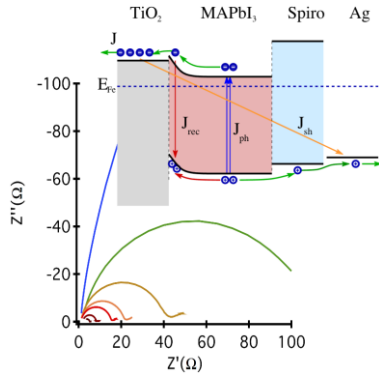
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Abstract

Halide perovskite materials have shown to be an excellent alternative for low-cost, solution processed high-efficiency solar cells. The performance of perovskite solar cell (PSC) is highly sensitive to several aspects; the deposition conditions, the substrate, humidity and even the efficiency of solvent extraction after solution deposition. However, the physical mechanism involved in the observed changes of efficiency with different deposition conditions have not been totally elucidated yet. In this work, PSCs were fabricated by the well-known Anti-solvent Deposition (AD) and the recently proposed Air-extraction Anti-solvent (AAD) process. Impedance analysis and J-V curve fittings were used to understand the photogeneration, charge transport, charge recombination, and charge leakage properties of PSCs fabricated by AD and AAD process. The improvement in the morphology of perovskite film promoted by AAD method, produces an increase in light absorption, resulting in an increment of short-circuit current density from 19.86 to 21.77mA/cm². At the same time, it reduces the recombination site density leading to an increase of open-circuit voltage from 0.957 to 0.995 V. In addition, it reduces the interstitial defects resulting in reduced leakage current, thus enhancing the FF from 66.7 to 72.6%. An overall increment in PCE of ~24% from 12.7% to 15.7% was obtained by the application of AAD technique. This study would open up doors for further improvement of the device and will help to understand the physical mechanism of operation in PSCs and its relation with the deposition method



Halide perovskite solar cells (PSCs) have made a rapid stride in recent years with the maximum power conversion efficiency (PCE)¹⁻⁴ reaching 22.1%^{5,6}, with further scope for improvement. This material shows excellent optoelectronic properties like, high absorption in the visible region, long diffusion length, and tunable optical band gap, which makes perovskite material a powerful candidate to boost the potential of photovoltaic (PV) technologies^{7,8}. Apart from the rigorous research involved in increasing the efficiency of PSCs, the study of its physical properties, holds the key for further improvement and better understanding of this incredible material. The charge carrier mobilities in perovskite devices are comparable to the inorganic semiconductors⁹⁻¹¹, thus showing improved charge collection efficiency at outer contacts. In addition, the high-performance of PSC is based on reduction of non-radiative bulk recombination,¹² suggesting the crucial role played by the recombination processes at outer contacts.

Several methodologies have been reported to improve the efficiency of PSCs; changing the composition of perovskite material by using different organic cation (MA⁺ or FA⁺)¹³⁻¹⁵, halide ions (I⁻, Br⁻ or Cl⁻)¹⁶⁻¹⁸, or inorganic cation (Cs⁺ or Rb⁺)¹⁹⁻²⁰, altering the architecture of the device i.e., the mesoscopic, planar or inverted configuration²¹⁻²³, different deposition strategies like single step deposition²⁴, two-step inter-diffusion²⁵, anti-

solvent based deposition²⁶, vacuum-assisted deposition²⁷ or solvent-solvent extraction²⁸, using different electron or hole transporting materials. Although, a considerable improvement in the performance of PSCs has been obtained, a complete understanding of the physical phenomenon involved in perovskite-based PV device still remains unresolved.

Impedance spectroscopy (IS) is an excellent and well-established technique for characterizing the electrochemical systems, being particularly advantageous to extract dynamic operating parameters in a variety of solar cells technologies^{29, 31}. IS captures the current response to small-amplitude modulating voltage stimulus. In order to interpret the data generated by this method, an equivalent circuit comprising of resistive and capacitive response element is used for fitting. For correct interpretation, different elements of the circuit have to be correlated with the physical mechanism of the device. Despite its interpretative potential, the impedance response of PSCs are yet to be resolved completely as the correlation between circuit elements and physical processes is not straightforward^{32,33,36}. However, recent studies have shown significant advances in studying the physical process occurring within the perovskite-based device. The dependence of high and low-frequency capacitance on the dielectric process and the interfacial charge accumulation within the perovskite device has been reported^{36, 37, 42}. The high and low-frequency resistance were reported to be related to the interface between the perovskite and extraction layer and the involved recombination process^{34,37}.

In this work, a systematic characterization and impedance analysis of PSCs fabricated by Anti-solvent Deposition (AD) and recently proposed Air-extraction Anti-solvent deposition (AAD) is reported. An increment in PCE from 12.7 to 15.7% corresponding to an increment of all the photovoltaic (PV) parameters (current density (J_{sc}), open-circuit

voltage (V_{oc}) and fill factor (FF)) has been observed with AAD technique when compared to the conventional AD method. A detailed interpretation of the structural, optical, and photoelectrochemical properties was carried out to elucidate the physical processes involved in the enhancement of PV performance. It would also act as a standard for further improvement of the device. Current-voltage (J-V) curve fitting based on impedance analysis, were carried out to have a better insight into the underlying physical mechanism with the two fabrication techniques. The impedance analysis indicates that, the improvement in morphology of perovskite film fabricated by AAD technique results in a higher photogeneration current (J_{ph}). At the same time, it reduces the recombination centers density with reduced grain boundaries due to enlarged crystals, resulting in higher open-circuit voltage (V_{oc}). Finally, the reduced leakage current results in an enhanced FF.

Morphological, optical and electrochemical analysis. Figure 1 depicts the surficial and cross-sectional SEM images - of perovskite film fabricated by AD and AAD method and statistical distribution of the grain size of the samples is shown in Figure S1. There is a clear effect of the deposition method on surface morphology of obtained film. The film obtained by AD method (Fig 1A, S1A) presents a grain size varying from 46 to 224 nm, with an average size of 94 nm, while the film prepared by the AAD technique, exhibits a considerable increment in grain size varying from 108 to 869 nm with an average size of 234 nm (see Fig 1B, S1B). It is desirable to note that the thickness of perovskite film (Figure 1C and D) is almost unaffected by the AAD method; both of them being ~ 200 nm, thus neglecting its effect on the increment in absorption.

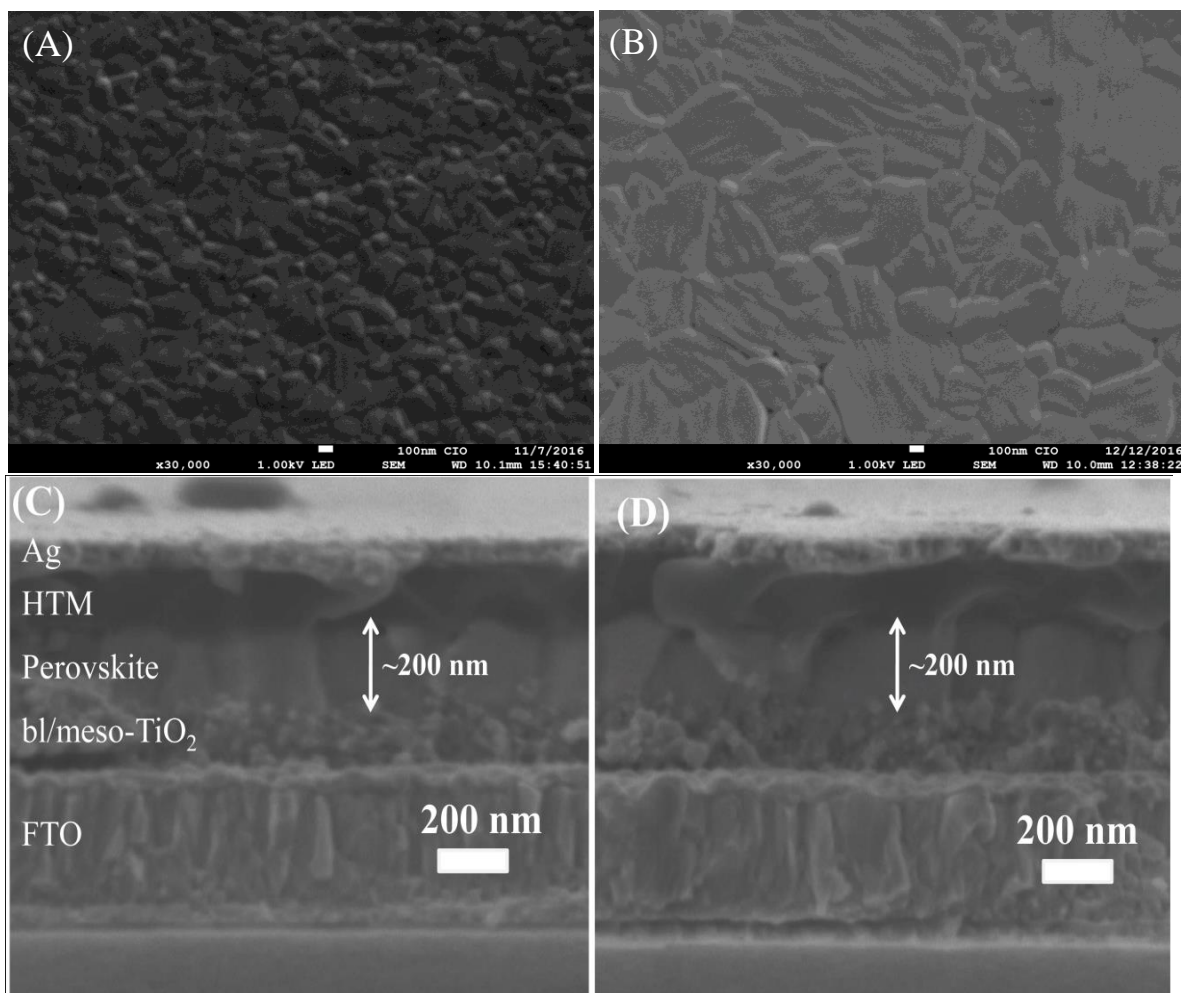


Figure 1 Top (A, B) and cross-sectional (C, D) SEM images of perovskite film fabricated by (A, C) conventional anti-solvent and (B, D) AAD process.

The absorption spectra of perovskite film fabricated by AD and AAD technique are shown in Figure 2A. Both samples are having a broad absorption band ranging from 300 to 800 nm with an absorption edge at 770 nm indicating a band gap of 1.6 eV. The use of AAD method results in an increment of absorption of around 9%. This increment in light absorption can be attributed to the improvement in the morphology of perovskite layer.³⁹⁻⁴¹

Figure 2B represents the typical reverse bias current density-voltage (J-V) curve for perovskite devices fabricated by AD and AAD methods. The average PV parameters of 15 samples and the best device of each batch are listed in Table 1, and the photovoltaic metrics

of 15 devices fabricated using both methods are presented in Figure S2. By employing the AAD technique, an increment in average photocurrent of ~10.65% from 19.62 to 21.71 mA/cm² was obtained. Also, an increment in average V_{oc} of ~ 3.32% from 960 to 993 mV and FF of ~9.42% from 65.73 to 71.92% was observed. Hence, the average photoconversion efficiency of device fabricated by AAD method increases by ~25.89% in comparison with the AD sample, reaching 15.1% from 12.32%. The champion cells fabricated by AD and AAD method provide a conversion efficiency of 13.13% and 16.40%. All the photovoltaic parameters follows a similar trend as the average parameters. Forward and reverse bias scan (Figure S3) indicate that the hysteresis is considerable reduced when the AAD method is applied.

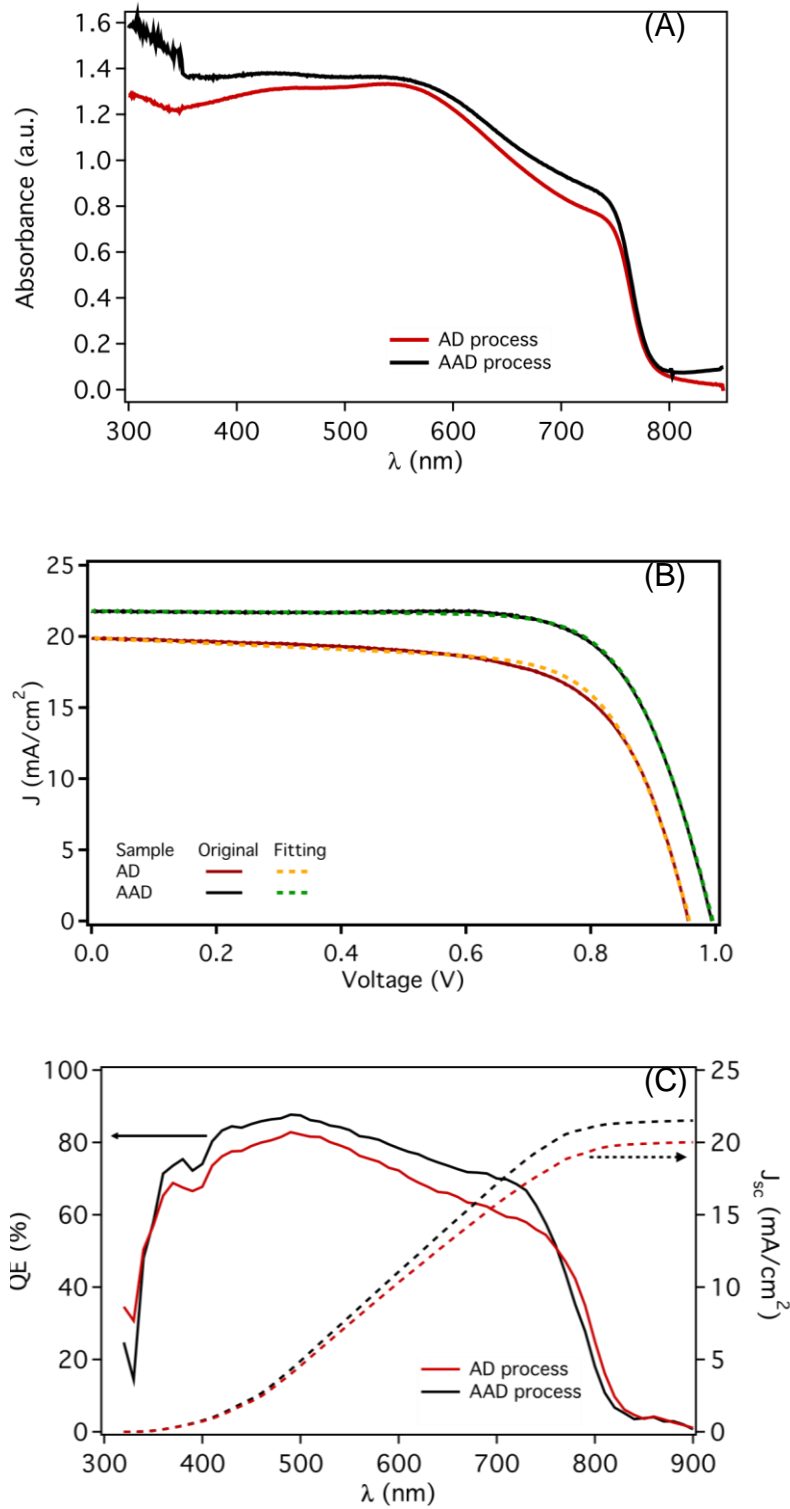


Figure 2 Optical and electrochemical measurements of the devices fabricated by AD and AAD processes, (A) Absorption spectra of the perovskite films; (B) Typical reverse bias J-V curves of PSCs with curve fitting using equation 4; and (C) Typical IPCE curves of the PSCs

Table 1 Average PV parameters of 15 cells with the best cell fabricated by anti-solvent and AAD method under uniform condition.

Deposition method		J_{sc} (mA/cm ²)	V_{oc} (V)	FF (%)	η (%)
AD	Average	19.62±0.31	0.960±0.01	65.73±1.13	12.32±0.45
	Best	20.21	0.968	67.23	13.15
AAD	Average	21.71±0.38	0.993±0.01	71.92±0.94	15.51±0.34
	Best	22.22	1.011	73.02	16.40

The current density is mainly dominated by two phenomena; the photogeneration (the process where photons are absorbed to generate electron-hole pairs) and the injection (the transfer of electrons and holes to the electron and hole transport material, respectively). To understand the photogeneration in terms of contribution of each absorbed wavelength, the incident photon to current conversion efficiency (IPCE), was measured. Figure 2C shows the representative IPCE curves and the integrated current of the samples under study. The cells fabricated by AD method presents an IPCE of more than 55% from 380 to 700 nm, reaching a maximum of 83% at 490 nm and down to zero at 800 nm. It completely matches with the absorption of perovskite material. With the use of AAD technique, an increment in IPCE of ~9.6% was obtained in the wavelength ranging from 350 to 750 nm. This increase in IPCE is the origin of the observed enhancement of photocurrent for the

samples fabricated by AAD technique, see Figure 2B, integrated current in Figure 2C and Table 1. It suggests that, most of the increase in IPCE is due to the enhancement in light absorption, see Figure 2A.

Impedance analysis. The impedance curve in PSCs have shown to be strongly affected by the measurement conditions.^{36, 37 42, 43} To simplify the analysis and to ensure a correct interpretation of the results, impedance spectra were recorded under different light intensities at open circuit condition, where the recombination process is dominant. Figure 3A shows an impedance plot as a function of irradiation intensity, in which the resistive component of the two arcs shrinks as the illumination increases. The equivalent circuit shown in Figure 3B was used to fit the impedance data where, R_s is the series resistance due to wire and contact resistance, C_g is the high-frequency capacitance interpreted as the geometric capacitance of the device; related to the dielectric properties of the perovskite^{36,42,47}, C_s is the low-frequency capacitance and is associated with the surface charge accumulation at the TiO_2 /perovskite interface^{37,42}. R_1 and R_2 represent the low and high-frequency resistance related to the recombination process at the interface of the perovskite and the extraction, in such a way that the total recombination resistance is $R_{rec}=R_1+R_2$.^{36,43}

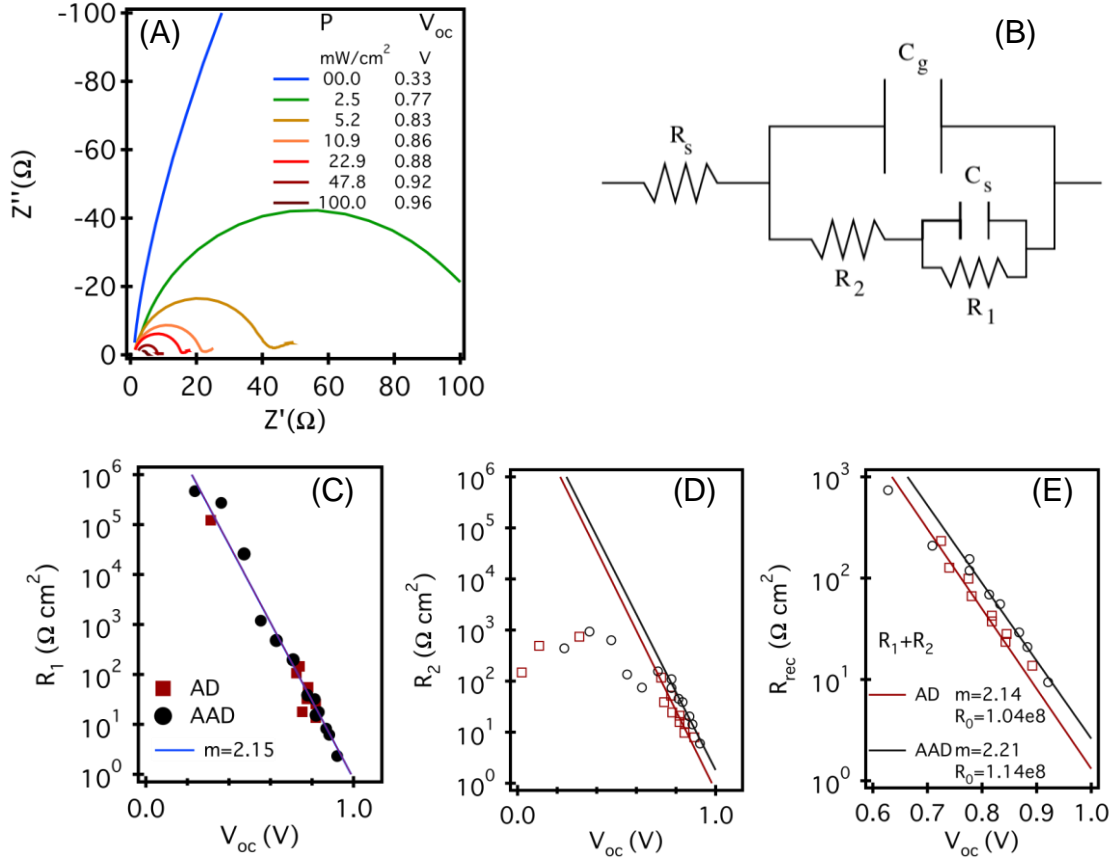


Fig 3 (A) Nyquist plot measured at open circuit conditions for different irradiation intensities corresponding to the samples fabricated by AAD process. (B) Equivalent circuit used to fit the impedance data. (C) Low-frequency resistance and (D) High-frequency resistance measured in samples made by AD method and AAD method showing the linear fit. (E) Calculated recombination resistances, with the corresponding linear fits.

According to Figure 3C, the resistance R_1 decreases exponentially with voltage and light intensity, following the expression^{36,43},

$$R = R_0 \exp\left(\frac{-qV}{mk_B T}\right) \quad (1)$$

where R_0 is the pre-exponential factor, q is the electron charge, k_B is the Boltzmann constant, T is the temperature and m is the ideality factor. This behavior indicates that R_1 is

related with the non-radiative recombination process.^{36,44} It could be observed from Figure 3C that both kinds of samples have the same behavior, showing that the recombination process at low frequency is not affected by the AAD method.

On the other hand, the high-frequency resistance R_2 (Figure 3D) has two characteristic regions, indicating two parallel processes, each one dominant at different open-circuit voltages. From 0 to 0.7 V, R_2 does not show a direct dependence on voltage, which further decreases for $V_{oc} > 0.4$ V. According to the literature, FF of PSC is dominated by the leakage process in this range of voltage and is characterized by a constant resistance, referred to as the shunt resistance (R_{sh})⁴⁴. Since there are two parallel processes inflicting R_2 and some of the points are lying in the transition region between these processes (0.4 to 0.7 V), it is not possible to correctly estimate the value of R_{sh} . For $V_{oc} > 0.7$ V, R_2 decreases exponentially with voltage and light intensity, following the equation 1, indicating that R_2 at such voltages is also related with the non-radiative recombination process^{43,44}. Our previous studies suggest that, the recombination resistance (R_{rec}) of PSCs is the addition of both resistances ($R_{rec} = R_1 + R_2$)³⁶. Figure 3E shows the R_{rec} in the region of voltages where the recombination process is dominant for both resistances. It is possible to observe that both samples are having almost the same slope. A very useful parameter to describe the recombination process in solar cell is the ideality factor (m)^{43,44}. From this parameter, it is possible to determine the origin of the recombination, being a band to band recombination (bulk recombination), when $m=1$ and band to defect recombination (which in the case of PSC has been ascribed to as surface recombination)^{36,42,44} when $m=2$. Using equation 1, the ideality factor was calculated, and was found to be, $m=2.14 \pm 0.17$ for AD and 2.21 ± 0.14 for AAD process. It indicates that the surface recombination is the dominant process in both kinds of cells.

However, AAD samples (S2) have slightly higher R_0 than the AD samples, indicating that recombination process is reduced with the AAD method. As per the literature, this recombination process occurs due to the accumulation of holes at the $\text{TiO}_2/\text{perovskite}$ interface.³⁶ One recurrent hypothesis is that, these holes accumulate at trap levels produced by movable defects like interstitial iodine^{44,46-50} in perovskite devices. It is considered as one of the most important source defects at the grain boundaries^{44,50}. Then, it can be presumed that, the improvement in morphology induced by the AAD process reduces the number of movable defects, resulting in the observed reduction of recombination process. Other approaches propose the formation of a valence band hole accumulation zone.^{36,42}

This increase in recombination resistance can also be described as a shift of R_{rec} to higher voltages, which corresponds to a shift in the Fermi level of 38 mV. This value perfectly matches with the increase in V_{oc} observed in the J-V curves. However, as previously stated by Garcia-Belmonte *et al.*, the voltage offset (ΔV_{oc}) observed in both J-V and R_2 curves is due to an energetic (ΔV_{E}) and a kinetic (ΔV_{kin}) voltage shift³⁰.

$$\Delta V_{\text{oc}} = \Delta V_{\text{E}} + \Delta V_{\text{kin}} \quad (2)$$

Absorption data indicates that $\Delta E_{\text{g}} = 0$ eV, which indicates that the increase in V_{oc} is exclusively caused by the reduction in the recombination process. This is corroborated by the fact that $\Delta V_{\text{oc}}=38$ mV exactly matches the shift in R_{rec} as observed in Fig. 3D

J-V modeling. To have a complete understanding of the variation of shunt and series resistances and their effect on the performance of PSC with respect to the AAD process, the

J-V curves were fitted using a simple model, considering the photogenerated current (J_{ph}), recombination current (J_{rec}), and shunt current (J_{sh})^{36,43}.

$$J = J_{ph} - J_{rec} - J_{sh} \quad (3)$$

$$J = J_{ph} - \frac{2k_B/q}{R_{rec}} - \frac{V_f}{R_{sh}} \quad (4)$$

where R_{rec} is estimated from the impedance analysis, R_{sh} is the shunt resistance, calculated from the fitting, and V_f is the applied voltage (V_{app}) corrected with the voltage drop due to series resistance (R_s)⁴⁴.

$$V_f = V_{App} - JR_s \quad (5)$$

The resulting curves are shown in Figure 2B. The model reproduces the J-V curve behavior of both kind of samples with almost accuracy, confirming that R_{rec} is the addition of the high and low-frequency resistance.

According to the fitting results shown in Table 2, R_s is $\sim 3 \Omega\text{cm}^2$. It indicates that the resistance from contacts and charge carrier transport within the cells are very small giving high PV performance, as reported previously⁴⁴. Additionally, the R_s related with transport resistance at contacts and wires is not modified by the use of AAD method as it can be expected. The R_{rec} , as previously mentioned, has a small increase of $\sim 170 \Omega\text{cm}^2$ at $V=0.7\text{V}$ which could be attributed to the reduction of grain boundaries. In addition, the R_{sh} of AAD samples is 7 times higher than the one obtained by AD (from 0.5 to 3.5 $\text{K}\Omega\text{cm}^2$). As this resistance is related to the leakage processes, this increase indicates the improvement in film quality obtained by AAD process reducing the pinholes and other short-circuit sources resulting in the mentioned FF enhancement.

Under open-circuit condition, the photogenerated current J_{ph} is completely suppressed by J_{rec} and J_{sh} ($J_{ph}=J_{rec(oc)}+J_{sh(oc)}$). Then, it is possible to estimate the J_{ph} and compare it with the measured J_{sc} . From the Table 2, it is observed that the AAD process effectively increases the J_{ph} from 20.0 to 21.8 mA/cm² which means an increase of 9% in the photo-generation. Such increment is in agreement with the IPCE and absorption increment discussed above. Under short-circuit conditions, a part of the photogenerated carriers recombines at the outer interface, while the main parts of the carriers are drained off. This implies that the measured short-circuit current is reduced by a term related to the carrier loss expressed by³⁶.

$$J_{sc} = J_{ph} - J_{rec(sc)} \quad (6)$$

The ratio between the recombination current and the photogenerated current gives the effective collection loss of the solar cell,

$$\alpha = \frac{J_{rec(sc)}}{J_{ph}} = \frac{J_{rec(sc)}}{J_{rec(oc)} + J_{sh(oc)}} \quad (7)$$

$$\alpha = 1 - \frac{J_{sc}}{J_{ph}} \quad (8)$$

This parameter will determine the difference between internal and external quantum efficiency. As observed in Table 2, the collection loss for AD and AAD samples are below 1% being a little lower for AAD samples, indicating that both samples are having very good charge extraction at the contacts.

Table 2: Calculated values of the photogenerated current and the resistances obtained from the J-V curve fitting

Sample	R_s Ωcm^2	R_{rec} (V=0.7V) Ωcm^2	R_{sh} $\text{K}\Omega\text{cm}^2$	J_{ph} mA/cm^2	α (%)	$1-\alpha$
AD	2.9	316	0.5	20.0	0.7	0.993
AAD	2.9	492	3.5	21.8	0.1	0.999

According to the experimental evidence described above, it is possible to conclude that, when AD samples are under light conditions, see Figure 4A, electron-hole pairs are photogenerated inside MAPbI_3 bulk (blue arrow). The holes move towards the spiro-OMeTAD (HTM, hole transporting material) which is further transported to the metallic contact. While, the electrons move towards the TiO_2 electrode, presumably following tunneling injection, where it will be given to the FTO, thus generating the current. However, PSCs have ionic defects like interstitial I^- that easily move under working conditions and accumulate at the TiO_2 /perovskite interface as a self-doping effect. These ions introduce trap levels near the valence band, where photogenerated holes accumulate favoring the recombination (red arrows). Additionally, some electrons leak in as shunt current (orange arrow) due to the imperfections of the perovskite films (like pin holes). When AAD method is employed, see Figure 4B, a considerable increase in the grain size is observed. As a consequence, the light absorption cross-section is increased resulting in an increase in the photogeneration directly improving the J_{sc} . Another consequence of the increase in crystal size

is the reduction of grain boundaries which act as the principal source of mobile defects. Then, the recombination is reduced at the outer interfaces resulting in a higher capability of accumulating electrons at the conduction band leading to an upshifting of the electron quasi-fermi level and thus increasing the V_{oc} . Finally, the improvement in the perovskite film quality results in a reduction of leakage sources leading to an increase in the FF. In this way, the AAD process improves the three photovoltaic parameters at the same time, resulting in a considerable enhancement in the photo conversion efficiency.

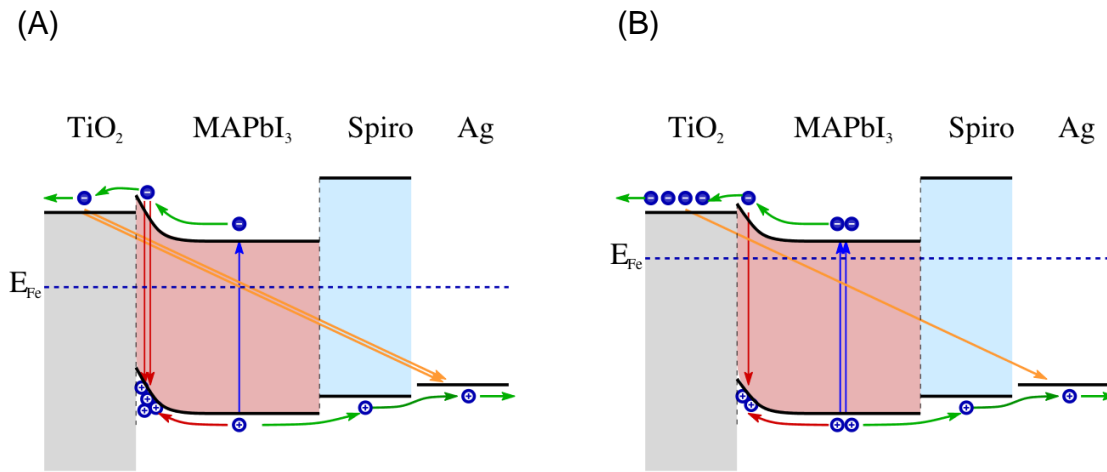


Fig 4 Illustrative energy diagram of PSC made by A) AD process and B) AAD process, showing the electron and hole flux for: extracted current J (green arrows), photogenerated currents J_{ph} (blue arrows), nonradiative recombination current J_{rec} (red arrows), and shortcircuit currents J_{sh} (orange arrows).

As conclusion, the photovoltaic properties of MAPbI_3 solar cells deposited by anti-solvent (AD) and air extraction anti-solvent method (AAD) were systematically studied. It was found that the samples made by AAD process have higher J_{sc} , V_{oc} , and FF. Impedance analysis and J-V curve fitting were performed to elucidate the physical mechanism within the device. The studies indicate that the improved morphology and enhanced crystallinity obtained by the AAD method induces higher absorption, resulting in an increase in J_{sc} from

19.8 to 21.7 mA/cm². At the same time, it reduces the recombination centers arising from the grain boundaries, resulting in a small increase of V_{oc} from 0.957 to 0.995 V. Finally, electron leakage is reduced, which results in an increase in FF from 66.7 to 72.6%. These three effects, result in an enhancement of PCE from 12.7 to 15.7 %. This work also highlights the importance of impedance spectroscopy in understanding the relationship between the deposition methods and the obtained morphology on the final cell performance.

Experimental Section

Perovskite film fabrication. CH₃NH₃I (Dyesol), PbI₂ (99.99%, Lumtec) and dimethyl sulfoxide (DMSO) (> 99.9%, Sigma-Aldrich) were dissolved in 1mL of anhydrous N,N-dimethylformamide (DMF) (>99%, Sigma-Aldrich) at 80°C for 2 h to prepare the perovskite solution. In the anti-solvent deposition approach (AD), 100 μL of the perovskite solution was spin coated on mesoporous TiO₂ at 5000 rpm for 40 s. During the spin coating process, 0.5 mL of ethoxyethane (95%, Sigma-Aldrich) was dropped instantaneously at the center of the substrate. The deposition resulted in a transparent film which was transferred onto a hotplate and heated at 100°C for 3 min. In the AAD approach³⁸, exactly the same procedure was followed but the whole process was executed under the intake of an air-extractor hood whose operation started a few seconds before the start of the spin coating process and was kept on until the end of the process.

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Supporting Information. Detailed experimental methodology , photovoltaic metrics of 15 devices

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